

## EAST Search History

S78	193	(US-20050023574-\$ or US-20040171177-\$ or US-20050001211-\$ or US-20040126617-\$ or US-20050230752-\$ or US-20050247982-\$ or US-20050145914-\$ or US-20050109743-\$ or US-20050258423-\$ or US-20040169023-\$ or US-20040147074-\$ or US-20040009632-\$ or US-20030201466-\$ or US-20030098496-\$ or US-20030034492-\$ or US-20050181599-\$ or US-20040211961-\$ or US-20050123791-\$ or US-20050095452-\$ or US-20050123795-\$ or US-20050002227-\$ or US-20040084080-\$ or US-20050221119-\$ or US-20030224202-\$ or US-20040195567-\$ or US-20040238823-\$).did. or (US-20050170205-\$ or US-20040108504-\$ or US-20050040399-\$ or US-20020192904-\$ or US-20050006648-\$ or US-20040183066-\$ or US-20040262667-\$ or US-20040164302-\$ or US-20050045729-\$ or US-20050095450-\$ or US-20040140547-\$ or US-20050214983-\$ or US-20040245526-\$ or US-20040238821-\$ or US-20040195572-\$ or US-20050221120-\$ or US-20050051870-\$ or US-20050279999-\$ or US-20050280002-\$ or US-20040207031-\$ or US-20050263771-\$ or US-20040222417-\$ or US-20050263773-\$ or US-20040222423-\$ or US-20050029601-\$ or US-20030201415-\$ or US-20030035314-\$).did. or (US-20020149044-\$ or US-20020173137-\$ or US-20050123794-\$ or US-20020093046-\$ or US-20050269572-\$ or US-20050274052-\$ or	US-PGPUB; USPAT	OR	ON	2006/07/21 11:12
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## EAST Search History

S79	121	S78 and (semiconductor and oxide and gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/21 11:15
S80	77	S78 and (semiconductor and (metal adj1 oxide) and gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/21 11:19
S81	2	10/367429 and (semiconductor and (metal adj1 oxide) and gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/21 11:24
S82	2	("6740924").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/07/21 11:23
S83	2	S81 and (semiconductor and (metal adj1 oxide) and gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/21 11:24
S84	1	S82 and (semiconductor and (metal adj1 oxide) and gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/24 08:18